

$^{162}\text{W}$   $\alpha$  decay

Type	Author	History Citation	Literature Cutoff Date
Full Evaluation	N. Nica	NDS 141, 1 (2017)	1-Feb-2017

Parent:  $^{162}\text{W}$ : E=0;  $J^\pi=0^+$ ;  $T_{1/2}=1.19$  s 12;  $Q(\alpha)=5677.3$  27; % $\alpha$  decay=45.2 6

$^{162}\text{W}$ -% $\alpha$  decay: from  $^{162}\text{Hf}$  Adopted Levels and based on 0.46 4 ([1981Ho10](#)), 0.49 4 ([1989Wo02](#)), and 0.44 2 ([1996Pa01](#)).

$T_{1/2}$ : from  $^{162}\text{Hf}$  Adopted Levels, Gammas dataset.

$Q_\alpha(^{162}\text{W})$ : from [2012Wa38](#).

Experimental methods:

[1973Ea01](#): Produced by  $^{144}\text{Sm}(^{24}\text{Mg},6\text{n})$ ;  $\alpha$ 's measured with Si detector.

[1975To05](#): Produced by  $^{156}\text{Dy}(^{16}\text{O},10\text{n})$ ;  $\alpha$ 's measured with Si detector.

[1979Ho10](#), [1981Ho10](#), [1981HoZM](#): Produced by  $^{58}\text{Ni}$  bombardment;  $\alpha$ 's measured with Si detector following velocity selector.

[1982De11](#): Produced by  $^{63}\text{Cu}$  bombardment.

[1989Wo02](#): Produced by  $^{110}\text{Cd}(^{58}\text{Ni},x)$ .

[1996Pa01](#): Produced by  $^{112}\text{Sn}(^{58}\text{Ni},x)$  or other reactions and separated in recoil mass separator.  $\alpha$ 's measured in silicon strip detector with parent-daughter correlation.

Other: [2015Da03](#) observe (among others) the 5536 $\alpha$  of  $^{162}\text{W}$  to  $^{158}\text{Hf}$  in  $\alpha$ - $\gamma$  coin measurements (Fig. 6a).

 $^{158}\text{Hf}$  Levels

E(level)	$J^\pi$
0	$0^+$

 $\alpha$  radiations

$E\alpha$	E(level)	$I\alpha^\dagger$	Comments
5536 3	0	100	$E\alpha$ : Weighted average of 5528 10 ( <a href="#">1975To05</a> ), 5538 5 ( <a href="#">1979Ho10</a> ), 5534 4 ( <a href="#">1982De11</a> ), and 5541 5 ( <a href="#">1996Pa01</a> ); other: 5530 ( <a href="#">1973Ea01</a> ).

<sup>†</sup> For absolute intensity per 100 decays, multiply by 0.452 6.